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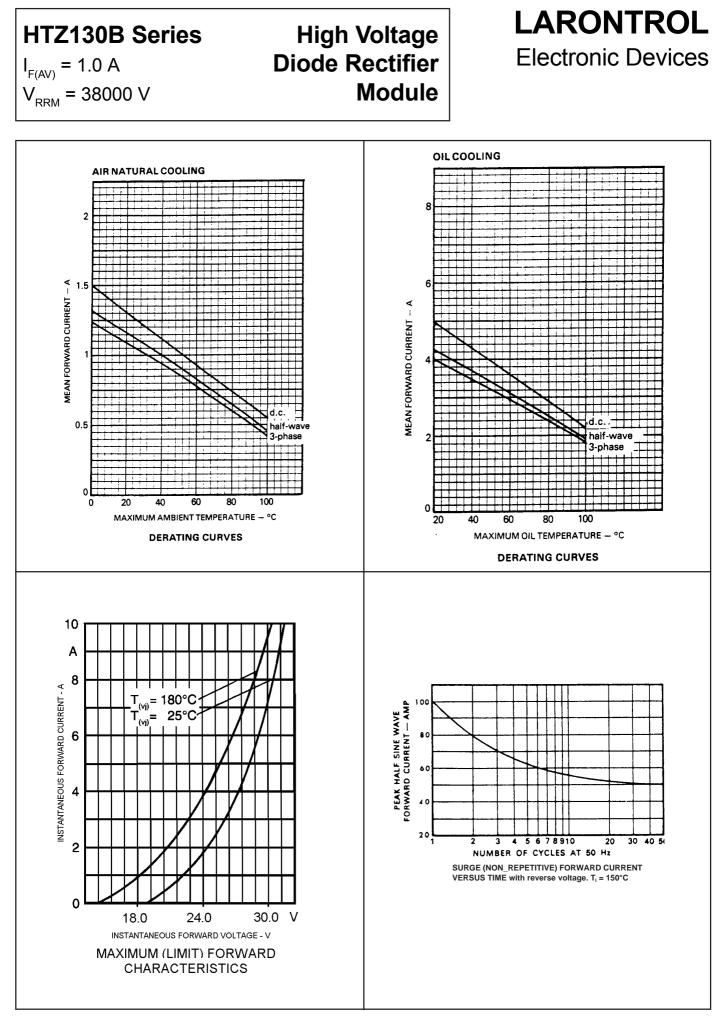
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HTZ130B Series I _{F(AV)} = 1.0 A V _{RRM} = 38000 V		High Voltage Diode Rectifier Module			LARONTROL Electronic Devices		
Type Number	Repetitive Peak	Minimum Avalanche Voltage V _{(BR)R}					
HTZ130B38 HTZ130B33 HTZ130B28 HTZ130B24	SK 33000 SK 28000	40800 36000 31200 26400			8		
CIRCUIT DIA	¢	NRRM					
$\begin{array}{llllllllllllllllllllllllllllllllllll$		rward current	Half wave resistiv T _{amb} = 35°C	ve load T _{amb} = 35°C	1.0 1.2 5.7	A A °C/W	
$\begin{array}{llllllllllllllllllllllllllllllllllll$		rward current	Half wave resistive load $T_{oil} = 60^{\circ}C$ $T_{oil} = 60^{\circ}C$		3.1 3.6 1.2	A A °C/W	
SURGE RATINGSI²tI²t for fusingIFSMSurge (non-repetitive) for) forward current	10 ms half sine T _{vj} = 150°C T _{vj} = 150°C		50 100	A²sec A	
TEMPERATURE AND FREQUENCY RATINGST_vjVirtual junction temperatureT_stgStorage temperature rangefFrequency range		erature	Forward (conducting) Reverse (blocking)		180 180 -40 to 100 20 to 400	°C °C °C Hz	
CHARACT V _{FM} I _{RM}	ERISTICS T _{case} = 25 Forward voltage Peak reverse current	°C unless otherwis	e stated At 2 Amps peak At V _{RRM} ; T _{case} = 15	50°C	max 24.0 max 0.5	V mA	
	ned Outlines nown are maximum in mm			79.5			
Weight typ.	: 0,38 Kg		O MOUNTIN TAPPED N4, 3 OFF	G BUSHES			
		1 П		—		June 1998	

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